

### INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

### APT50M80LVFR

### FEATURES

- Drain Current –I\_D= 58A@ T\_C=25 $^\circ\!\mathrm{C}$
- Drain Source Voltage-: V<sub>DSS</sub>=500V(Min)
- Static Drain-Source On-Resistance : R<sub>DS(on)</sub> =0.08 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

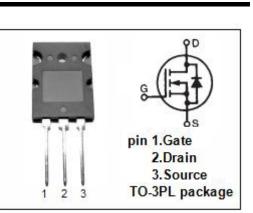
• Designed for use in switch mode power supplies and general purpose applications.

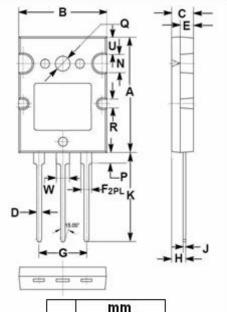
SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	500	V		
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V		
ID	Drain Current-Continuous	58	A		
I <sub>DM</sub>	Drain Current-Single Pluse	232	А		
PD	Total Dissipation @Tc=25°C 625		W		
TJ	Max. Operating Junction Temperature	-55~150	°C		
T <sub>stg</sub>	Storage Temperature	-55~150	°C		

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.20	°C/W





	mm	
DIM	MIN	MAX
Α	25.50	26.50
В	19.80	20.20
С	4.50	5.50
D	0.90	1.10
E	2.80	3.20
F	2.40	2.60
G	10.80	11.00
Н	3.10	3.30
J	0.50	0.70
Κ	20.00	21.00
N	3.90	4.50
P	2.40	2.60
Q	3.10	3.50
R	1.90	2.60
U	3.90	4.10
W	2.90	3.25



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#### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	500		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 2.5mA	2	4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =29A		0.08	Ω
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS}$ = 500V; $V_{GS}$ = 0 $V_{DS}$ = 400V; $V_{GS}$ = 0@T <sub>C</sub> =125°C		250 1000	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> =-58A; V <sub>GS</sub> = 0		1.3	V

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